CS220-10B CS220-10D CS220-10M CS220-10N

SILICON CONTROLLED RECTIFIERS 10 AMP, 200 THRU 800 VOLT

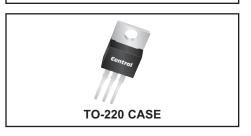


www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CS220-10B series types are epoxy molded SCRs designed for sensing circuit and control system applications.

MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T _C =25°C unless otherwise noted)			CS220				
Peak Renetiti	ve Off-State Voltage	SYMBOL V _{DRM} , V _{RRM}	<u>-10B</u> 200	<u>-10D</u> 400	<u>-10M</u> 600	<u>-10N</u> 800	UNITS V
•	e Current (T _C =90°C)	I _T (RMS)		1			A
Peak One Cycle Surge Current, t=10ms		ITSM	100			Α	
I ² t Value for Fusing, t=10ms		I ² t		50			A ² s
	ower Dissipation, tp=10µs	P_{GM}		40			W
Average Gate Power Dissipation		P _{G(AV)}		1.0			W
_	I Gate Current, tp=10µs	I _{FGM}		4.	.0		Α
Peak Forward Gate Voltage, tp=10µs		V _{FGM}		16			V
Peak Reverse Gate Voltage, tp=10µs		V _{RGM}		5.0			V
Critical Rate of Rise of On-State Current		di/dt		50			A/µs
Operating Junction Temperature		$T_{.1}$	-40 to +125			°C	
Storage Temperature		T _{stg}	-40 to +150			°C	
Thermal Resistance		Θ_{JA}		60			°C/W
Thermal Resistance		ΘJC	2.5			°C/W	
ELECTRICAL CHARACTERISTICS: (T _C =25°C unless otherwise noted)							
SYMBOL	TEST CONDITIONS	MIN	se notea)		ΑX		UNITS
I _{DRM} , I _{RRM}	Rated V _{DRM} , V _{RRM}			1	0		μΑ
I _{DRM} , I _{RRM} Rated V _{DRM} , V _{RRM} , T _C =12		5°C		2.	.0		mA
I_{GT}	V_D =12V, R_L =33 Ω			1	5		mA
lΗ	I _T =100mA			3	0		mA
V_{GT}	V_D =12V, R_L =33 Ω			1.	.5		V
V_{TM}	I _{TM} =20A, tp=10ms			1.	.6		V
dv/dt	V _D = ² / ₃ Rated V _{DRM} , T _C =125°	°C 200					V/µs

CS220-10B CS220-10D CS220-10M

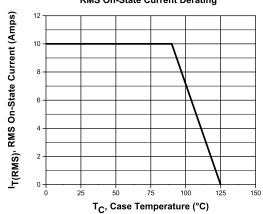
SILICON CONTROLLED RECTIFIERS 10 AMP, 200 THRU 800 VOLT

CS220-10N

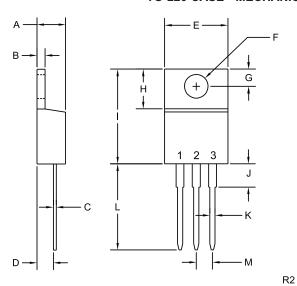


TYPICAL ELECTRICAL CHARACTERISTICS

RMS On-State Current Derating



TO-220 CASE - MECHANICAL OUTLINE



DIMENSIONS									
	INCHES		MILLIMETERS						
SYMBOL	MIN	MAX	MIN	MAX					
Α	0.170	0.190	4.31	4.82					
В	0.045	0.055	1.15	1.39					
С	0.013	0.026	0.33	0.65					
D	0.083	0.107	2.10	2.72					
Е	0.394	0.417	10.01	10.60					
F (DIA)	0.140	0.157	3.55	4.00					
G	0.100	0.118	2.54	3.00					
Н	0.230	0.270	5.85	6.85					
	0.560	0.625	14.23	15.87					
J	-	0.250	-	6.35					
K	0.025	0.038	0.64	0.96					
L	0.500	0.579	12.70	14.70					
М	0.090	0.110	2.29	2.79					

TO-220 (REV: R2)

- LEAD CODE:
- 1) Cathode
- 2) Anode
- 3) Gate Tab is common to pin 2

MARKING: FULL PART NUMBER

R1 (24-October 2013)